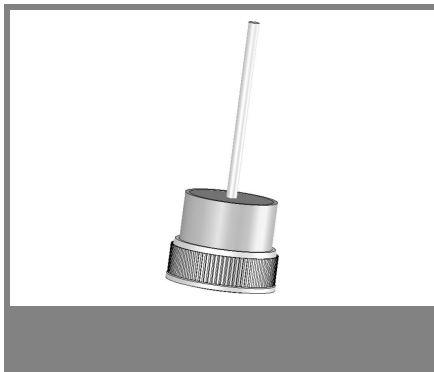


# BYP 35A05...BYP 35K6



Type	Wired to ANODE	Wired to CATHODE	Repetitive peak reverse voltage $V_{RRM}$ V	Surge peak reverse voltage $V_{RSM}$ V	Maximum forward voltage $T_j = 25\text{ }^\circ\text{C}$ $I_F = 35\text{ A}$ $V_F$ V
BYP 35	BYP 35A05	BYP 35K05	50	60	1,1
BYP 35	BYP 35A1	BYP 35K1	100	120	1,1
BYP 35	BYP 35A2	BYP 35K2	200	240	1,1
BYP 35	BYP 35A3	BYP 35K3	300	360	1,1
BYP 35	BYP 35A4	BYP 35K4	400	480	1,1
BYP 35	BYP 35A6	BYP 35K6	600	700	1,1

## Silicon Press-Fit-Diodes

### BYP 35A05...BYP 35K6

**Forward Current: 35 A**

**Reverse Voltage: 50 to 600 V**

Publish Data

### Features

- max. solder temperature 260°C, mac. 5s
- UL classification 94V-0
- Standard packaging: bulk

### Mechanical Data

- Metal press-fit case with plastic cover
- Weight approx. 8 g
- Terminals: plated terminals solderable per IEC 68-2-20
- Mounting position : any

Absolute Maximum Ratings		$T_c = 25\text{ }^\circ\text{C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
$I_{FAV}$	Max. averaged fwd. current, R-load, $T_c = 150\text{ }^\circ\text{C}$	35	A
$I_{FRM}$	Repetitive peak forward current $f > 15\text{ Hz}^{1)}$	110	A
$I_{FSM}$	Peak fwd. surge current 50 Hz half sinus-wave	360	A
$I^2t$	Rating for fusing, $t < 10\text{ ms}$	660	A <sup>2</sup> s
$R_{thA}$	Thermal resistance junction to case	0,8	K/W
$T_j$	Operating junction temperature	- 50 ... + 215	°C
$T_s$	Storage temperature	- 50 ... + 215	°C

Characteristics		$T_c = 25\text{ }^\circ\text{C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
$I_R$	Maximum leakage current, $T_A 25\text{ }^\circ\text{C}$ ; $V_R = V_{RRM}$	100	$\mu\text{A}$

